BOURNS®

- Designed for Complementary Use with BD646, BD648, BD650 and BD652
- 62.5 W at 25°C Case Temperature
- 8 A Continuous Collector Current
- Minimum h_{FE} of 750 at 3V, 3 A

TO-220 PACKAGE (TOP VIEW) B C E 3

Pin 2 is in electrical contact with the mounting base.

MDTRACA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING			VALUE	UNIT	
	BD645		80		
Collector-base voltage (I _E = 0)	BD647	V	100	V	
	BD649	V _{CBO}	120		
	BD651	6.0	140		
Collector-emitter voltage (I _B = 0)	BD645	- 17	60	V	
	BD647	V	80		
	BD649	V_{CEO}	100		
	BD651		120		
Emitter-base voltage		V _{EBO}	5	V	
Continuous collector current		I _C	8	Α	
Peak collector current (see Note 1)		I _{CM}	12	Α	
Continuous base current		I _B	0.3	Α	
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)			62.5	W	
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)			2	W	
Unclamped inductive load energy (see Note 4)			50	mJ	
Operating junction temperature range		T _j	-65 to +150	°C	
Storage temperature range			-65 to +150	°C	
Lead temperature 3.2 mm from case for 10 seconds		T _L	260	°C	

NOTES: 1. This value applies for $t_p \le 0.3$ ms, duty cycle $\le 10\%$.

- 2. Derate linearly to 150°C case temperature at the rate of 0.4 W/°C.
- 3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.
- 4. This rating is based on the capability of the transistor to operate safely in a circuit of: L = 20 mH, $I_{B(on)}$ = 5 mA, R_{BE} = 100 Ω , $V_{BE(off)}$ = 0, R_S = 0.1 Ω , V_{CC} = 20 V.



electrical characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER TEST CONDITIONS			MIN	TYP	MAX	UNIT			
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C = 30 mA	I _B = 0	(see Note 5)	BD645 BD647 BD649 BD651	60 80 100 120			V
I _{CEO}	Collector-emitter cut-off current	$V_{CE} = 30 \text{ V}$ $V_{CE} = 40 \text{ V}$ $V_{CE} = 50 \text{ V}$ $V_{CE} = 60 \text{ V}$	$I_{B} = 0$ $I_{B} = 0$ $I_{B} = 0$ $I_{B} = 0$		BD645 BD647 BD649 BD651			0.5 0.5 0.5 0.5	mA
Ісво	Collector cut-off current	$V_{CB} = 40 \text{ V}$ $V_{CB} = 50 \text{ V}$ $V_{CB} = 60 \text{ V}$	$I_{E} = 0$	$T_{C} = 150^{\circ}\text{C}$ $T_{C} = 150^{\circ}\text{C}$ $T_{C} = 150^{\circ}\text{C}$ $T_{C} = 150^{\circ}\text{C}$	BD645 BD647 BD649 BD651 BD645 BD647 BD649 BD651			0.2 0.2 0.2 0.2 2.0 2.0 2.0 2.0	mA
I _{EBO}	Emitter cut-off current Forward current	V _{EB} = 5 V	I _C = 0	(see Notes 5 and	3			5	mA
h _{FE}	transfer ratio	V _{CE} = 3 V	$I_C = 3 A$	(see Notes 5 and 6) 7		750			
V _{CE(sat)}	Collector-emitter saturation voltage	$I_B = 12 \text{ mA}$ $I_B = 50 \text{ mA}$	$I_C = 3 A$ $I_C = 5 A$	(see Notes 5 and	(6)			2 2.5	V
V _{BE(sat)}	Base-emitter saturation voltage	I _B = 50 mA	I _C = 5 A	(see Notes 5 and 6)				3	V
V _{BE(on)}	Base-emitter voltage	V _{CE} = 3 V	I _C = 3 A	(see Notes 5 and	16)			2.5	V

NOTES: 5. These parameters must be measured using pulse techniques, $t_p = 300 \mu s$, duty cycle $\leq 2\%$.

thermal characteristics

PARAMETER		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	R _{eJC} Junction to case thermal resistance			2.0	°C/W
$R_{\theta JA}$	Junction to free air thermal resistance			62.5	°C/W

^{6.} These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

COLLECTOR-EMITTER SATURATION VOLTAGE

TYPICAL CHARACTERISTICS

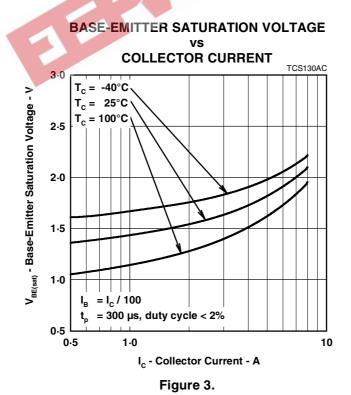
TYPICAL DC CURRENT GAIN COLLECTOR CURRENT TCS130AD 50000 -40°C 25°C $T_c =$ $T_c = 100$ °C h_{FE} - Typical DC Current Gain 10000 1000 3 V = 300 μs, duty cycle < 2% 100 1.0 10 0.5 I_c - Collector Current - A

Figure 1.

COLLECTOR CURRENT 2-0 $t_p = 300 \, \mu s, \, duty \, cycle < 2\%$ $t_p = 1.0$ 1-5 $T_c = -40^{\circ}C$ $T_c = 100^{\circ}C$ $T_c = 100^{\circ}C$

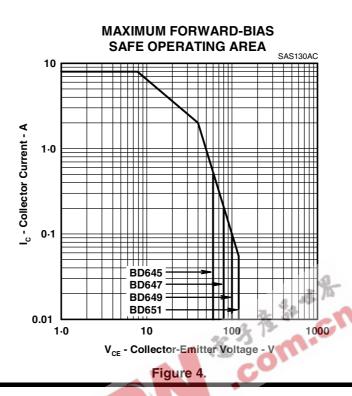
Figure 2.

I_c - Collector Current - A



PRODUCT INFORMATION

MAXIMUM SAFE OPERATING REGIONS



THERMAL INFORMATION

MAXIMUM POWER DISSIPATION CASE TEMPERATURE TIS130AC 80 P_{tot} - Maximum Power Dissipation - W 70 60 50 40 30 20 10 0 0 25 75 100 125 150 $\rm T_{\rm C}$ - Case Temperature - $^{\circ}\rm C$

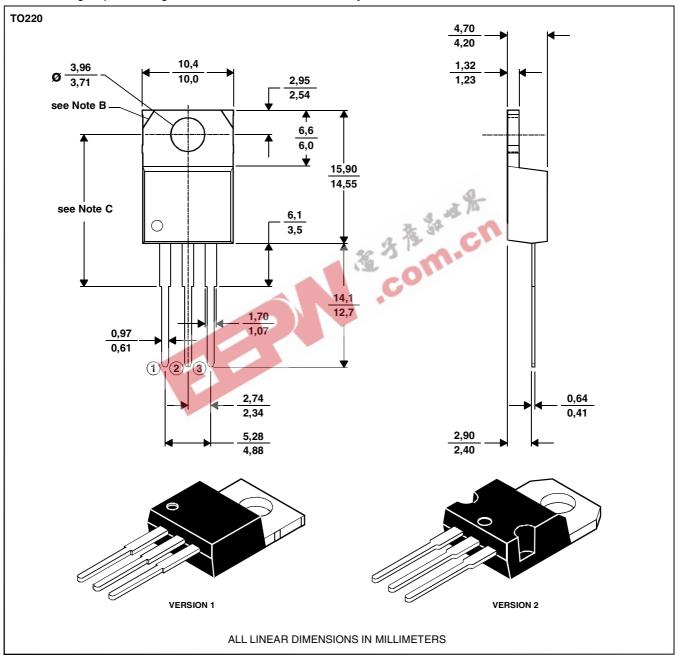
Figure 5.

MECHANICAL DATA

TO-220

3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTES: A. The centre pin is in electrical contact with the mounting tab.

- B. Mounting tab corner profile according to package version.
- C. Typical fixing hole centre stand off height according to package version.

Version 1, 18.0 mm. Version 2, 17.6 mm.

MDXXBE